L Number	Hits	Search Text	DB	Time stamp
-	2	5436467.pn.	USPAT;	2004/07/15 11:57
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	5	553982.pn.	USPAT;	2004/07/15 11:58
		333302.pm.	US-PGPUB;	2001,0,710 11,00
			EPO; JPO;	•
			DERWENT;	
			IBM_TDB	
-	2	6096965.pn.	USPAT;	2004/07/15 11:58
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	2	thin adj alternating adj layers adj (si or	USPAT;	2004/07/15 12:01
		silicon) adj (sic or (silicon adj	US-PGPUB;	
		carbide))	EPO; JPO;	
			DERWENT; IBM TDB	
_	n	thin adj alternating adj films adj (si or	USPAT;	2004/07/15 12:00
		silicon) adj (sic or (silicon adj	US-PGPUB;	
		carbide))	EPO; JPO;	
			DERWENT;	
1	_ `	And and signature of the control of	IBM_TDB	2004/07/15 12 22
-	0	thin adj films adj (si or silicon) adj (sic or (silicon adj carbide))	USPAT; US-PGPUB;	2004/07/15 12:00
		(Sic Of (Silicon ad) Carbide))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	thin adj layers adj (si or silicon) adj	USPAT;	2004/07/15 12:00
		(sic or (silicon adj carbide))	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	4	alternating adj layers adj (si or silicon)	USPAT;	2004/07/15 12:01
		adj (sic or (silicon adj carbide))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	_ ر	alternating adj films adj (si or silicon)	IBM_TDB USPAT;	2004/07/15 12:01
	Ĭ	adj (sic or (silicon adj carbide))	US-PGPUB;	2001,01,20 12101
			EPO; JPO;	,
			DERWENT;	
		(4) in a si a 16 a marking a si 1 a mark 1 a mark	IBM_TDB	2004/07/15 12:01
-	2	(thin adj alternating adj layers) with ((si or silicon) adj (sic or (silicon adj	USPAT; US-PGPUB;	2004/07/15 12:01
		carbide)))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	(thin adj alternating adj films) with ((si	USPAT;	2004/07/15 12:01
		or silicon) adj (sic or (silicon adj	US-PGPUB; EPO; JPO;	
		Calbine()	DERWENT;	
			IBM_TDB	•
-	0	(alternating adj films) with ((si or	USPAT;	2004/07/15 12:03
		silicon) adj (sic or (silicon adj	US-PGPUB;	
		carbide)))	EPO; JPO; DERWENT;	
			IBM TDB	
-	7	(alternating adj layers) with ((si or	USPAT;	2004/07/15 12:03
	1	silicon) adj (sic or (silicon adj	US-PGPUB;	
		carbide)))	EPO; JPO;	
			DERWENT;	
1_	Δ.	(thin adj layers) with ((si or silicon)	IBM_TDB USPAT;	2004/07/15 12:03
	1	adj (sic or (silicon adj carbide)))	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
			IBM_TDB	<u> </u>

-	17	(thin adj films) with ((si or silicon) adj (sic or (silicon adj carbide)))	USPAT; US-PGPUB;	2004/07/15 12:04
			EPO; JPO; DERWENT; IBM TDB	
-	15	(alternating) with ((si or silicon) adj (sic or (silicon adj carbide)))	USPĀT; US-PGPUB;	2004/07/15 12:15
			EPO; JPO; DERWENT; IBM TDB	
-	20	(alternating) same ((si or silicon) adj (sic or (silicon adj carbide)))	USPAT; US-PGPUB;	2004/07/15 12:03
			EPO; JPO; DERWENT;	
-	0	(alternating adj films) same ((si or silicon) adj (sic or (silicon adj	IBM_TDB USPAT; US-PGPUB;	2004/07/15 12:03
		carbide)))	EPO; JPO; DERWENT;	
_	10	(alternating adj layers) same ((si or silicon) adj (sic or (silicon adj	IBM_TDB USPAT; US-PGPUB;	2004/07/15 12:15
		carbide)))	EPO; JPO; DERWENT;	
-	23	(thin adj layers) same ((si or silicon) adj (sic or (silicon adj carbide)))	IBM_TDB USPAT; US-PGPUB;	2004/07/15 12:03
			EPO; JPO; DERWENT;	
-	40	(thin adj films) same ((si or silicon) adj (sic or (silicon adj carbide)))	IBM_TDB USPAT; US-PGPUB;	2004/07/15 12:23
			EPO; JPO; DERWENT;	
_	2	(thermoelectric adj module) with ((si or silicon) adj (sic or (silicon adj	IBM_TDB USPAT; US-PGPUB;	2004/07/15 12:24
		carbide)))	EPO; JPO; DERWENT;	
-	2	(thermoelectric adj module) same ((si or silicon) adj (sic or (silicon adj	IBM_TDB USPAT; US-PGPUB;	2004/07/15 12:24
		carbide)))	EPO; JPO; DERWENT; IBM TDB	
_	8	(thermoelectric adj module) and ((si or silicon) adj (sic or (silicon adj	USPAT; US-PGPUB;	2004/07/15 12:31
		carbide)))	EPO; JPO; DERWENT; IBM TDB	
-	70	(thermoelectric) and ((si or silicon) adj (sic or (silicon adj carbide)))	USPAT; US-PGPUB;	2004/07/15 12:37
			EPO; JPO; DERWENT; IBM TDB	
-	127	(thermoelectric) and ((si or silicon) near (sic or (silicon adj carbide)))	USPĀT; US-PGPUB;	2004/07/15 13:39
			EPO; JPO; DERWENT; IBM TDB	
-	524	(thermoelectric) and ((si or silicon) with (sic or (silicon adj carbide)))	USPAT; US-PGPUB;	2004/07/15 13:40
			EPO; JPO; DERWENT; IBM_TDB	
-	113	<pre>(thermoelectric) and ((si or silicon) with (sic or (silicon adj carbide))) and alternating</pre>	USPĀT; US-PGPUB; EPO; JPO;	2004/07/15 13:40
		arcornacing	DERWENT; IBM_TDB	